

High Voltage 3-Phase Motor Drivers

Features and Benefits

- Built-in bootstrap diodes with limit resistors
- Built-in protection circuit for controlling power supply voltage drop on VCC and VB (UVLO)
- Built-in Thermal Shutdown (TSD)
- Built-in Current Limiter (OCL)
- Built-in Overcurrent Protection (OCP)
- 7.5 V regulated output
- Output of fault signal during operation of protection circuit
- Small SOP package

Package: 27-pin SOP



Not to scale

Description

The SX68000MH series provides the solution for controlling 3-phase full bridges that utilize MOSFETs rated at 250 V/2 A, 500 V/1.5 A, or 500 V/2.5 A.

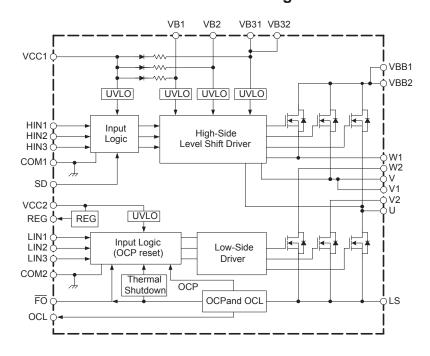
The IC includes in a single package: protection functions such as UVLO (protection circuit for controlling power supply voltage drop), OCP (overcurrent protection), TSD (thermal shutdown), and OCL (current limiting), and a pre-driver with $\overline{\rm FO}$ (Fault Output) terminal and bootstrap diodes with limit resistors.

The SX68000MH series is packaged in a fully-molded SOP with 27 pins at 1.2 mm pitch. Body size: $22 \times 14.1 \times 2.1$ mm.

Applications

- Small motor control:
- Air conditioning fan
- White goods cooling fans
- Ventilation blowers

Functional Block Diagram



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Selection Guide (Values at $T_A = 25$ °C)

Rating		ing					Thermal Resistance		
Part Number	(V)	(A)	MOSFET V _{DSS} (V)	I _O (A)	I _{OP} (A)	P _D (W)	Junction to Case, R _{θJC} (°C/W)	Junction to Ambient, R _{θJA} (°C/W)	
SX68001MH	250	2	250	2	3				
SX68002MH	500	1.5	500	1.5	2.25	3	15	41.7	
SX68003MH	500	2.5	500	2.5	3.75				

Absolute Maximum Ratings, valid at T_A = 25°C

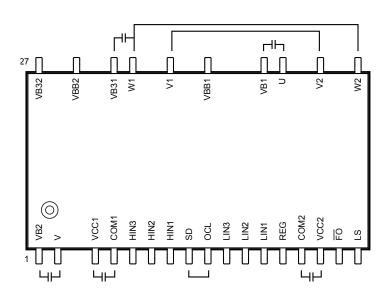
Characteristic	Symbol		Notes	Rating	Unit
		SX68001MH		250	V
MOSFET Breakdown Voltage	V_{DSS}	SX68002MH	I _D = 100 μA	500	V
		SX68003MH		500	V
Logic Supply Voltage	V _{CC}	VCC to COM		20	V
Bootstrap Voltage	V_{BS}	VB to high side	e (U,V,W)	20	V
		SX68001MH		2	Α
Output Current (Continuous)	Io	SX68002MH	T _C = 25°C	1.5	Α
		SX68003MH		2.5	Α
		SX68001MH		3	Α
Output Current (Pulsed)	I _{OP}	SX68002MH	t _W ≤ 100 μs, 1% duty cycle	2.25	Α
		SX68003MH		3.75	Α
Output Current for Regulator	I _{REG}			35	mA
Input Voltage	V_{IN}	LINx, HINx, F	Ō, SD, LS pins	-0.5 to 7	V
Maximum Allowable Power Dissipation*	P_D	T _A = 25°C		3	W
Thermal Resistance (Junction to Case)*	R _{0j-c}	All circuits ope	erating	15	°C/W
Thermal Resistance (Junction to Ambient)*	$R_{\theta j\text{-a}}$	All circuits ope	erating	41.7	°C/W
Case Operating Temperature	T _{OP}			-20 to 100	°C
Junction Temperature (MOSFET)	TJ			150	°C
Storage Temperature	T _{stg}			-40 to 150	°C

^{*}Mounted on 1.6 mm thick CEM-3 PCB, with 35 µm thick copper layer, without overmolding, in still air.

Recommended Operating Conditions

Characteristic	Symbol		Conditions	Min.	Тур.	Max.	Unit
		SX68001MH		-	140	200	V
Main Supply Voltage	V _{BB}	SX68002MH	VBB to LS	_	280	400	V
		SX68003MH		_	280	400	V
Logic Supply Voltage	V _{CC}		VCC to COM	13.5	_	16.5	V
Dead Time	t _{DEAD}			1.5	_	_	μs
Bootstrap Capacitor	C _{BOOT}			1	_	_	μF
Pull-up Resistor (FO pin)	R _{FO}			3.3	_	10	kΩ
Capacitor (FO pin)	C _{FO}			0.001	_	0.01	μF
		SX68001MH		0.45	_	_	Ω
Shunt Resistor (LS pin)	R _S	SX68002MH	V _{LS} ≤ 1 V	0.6	_	_	Ω
		SX68003MH		0.36	_	_	Ω

Pin-out Diagram

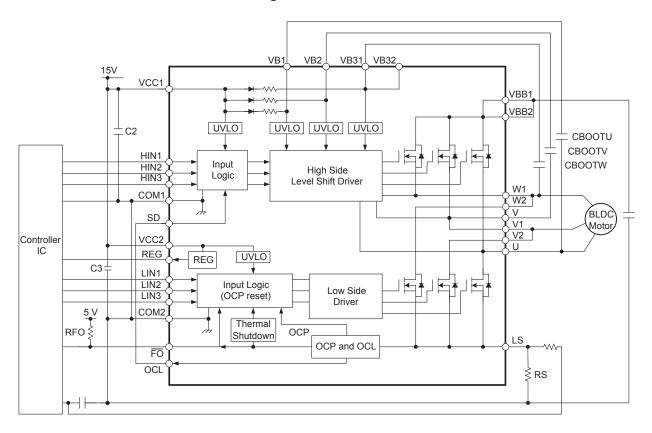


Terminal List Table

Number	Name	Function	Number	Name	Function
1	VB2	High-side bootstrap terminal (V phase)	14	COM2	Low-side GND terminal
2	V	Output of V-phase	15	VCC2	Low-side logic supply voltage
3	VCC1	High-side logic supply voltage	16	FO	Fault signal output (open collector output)
4	COM1	High-side logic GND terminal	17	LS	Low-side MOSFET source terminal
5	HIN3	High-side input terminal (W-phase)	18	W2	Output of W phase (connect to W1)
6	HIN2	High-side input terminal (V-phase)	19	V2	Output of V phase (connect to V1)
7	HIN1	High-side input terminal (U-phase)	20	U	Output of U phase
8	SD	High-side shut down input	21	VB1	High-side bootstrap terminal (U phase)
9	OCL	Current limiter signal output (CMOS output)	22	VBB1	Main supply voltage 1 (connect VBB2 externally)
10	LIN3	Low-side input terminal (W phase)	23	V1	Output of V phase (connect to V2)
11	LIN2	Low-side input terminal (V phase)	24	W1	Output of W phase (connect to W2)
12	LIN1	Low-side input terminal (U phase)	25	VB31	High side bootstrap terminal (W phase)
12	DEC	7.5.V regulator output	26	VBB2	Main supply voltage 2 (connect VBB1 externally)
13	REG	REG 7.5 V regulator output		VB32	High side bootstrap terminal (W phase)

All performance characteristics given are typical values for circuit or system baseline design only and are at the nominal operating voltage and an ambient temperature, T_A, of 25°C, unless otherwise stated.

Typical Application Circuit Using current limiter function



To avoid malfunctions or permanent damage to the IC, observe the following guidelines for layout of the PCB:

- W1 and W2, as well as V1 and V2 must be externally connected to each other.
- If not using the Current Limiter (OCL) function, leave the OCL and SD pins open, but the SD pin should be connected to GND if significant external noise is observed.
- Place a pull-up resistor, RFO, between the 5 V or 3.3 V supply and the IC, selected according to anti-noise characteristics, even though a 1 MΩ pull-up resistor is built-in at FO pin. Note that connecting to the 5 V or 3.3 V supply without a pull-up resistor disables the TSD function (however, low-side UVLO protection and OCP function remain active).
- To avoid malfunctions resulting from noise interference, place a 0.001 to 0.01 μF ceramic capacitor (C1) between the FO and COM2 pins.
- To avoid malfunctions resulting from noise interference, the traces must be as short as possible between the IC and the bootstrap capacitors, CBOOTx (≈1 µF).
- One of the bootstrap capacitors for the W phase can be populated between pin 24 (W1) and pin 25 (VB31). Also, because pin 27 (VB32) and pin 25 are internally connected, pin 27 can be left open.
- To avoid malfunctions resulting from noise interference, place a 0.01 to 0.1 μF ceramic capacitor between the VCC1 and COM1 (C2), as well as the VCC2 and COM2 (C3) pins. Also, the traces between them must be as short as possible.
- To avoid malfunctions resulting from noise interference, the traces between the current sense resistor RS, which is placed between the LS and COM2 pins, and the IC must be as short and wide as possible.
- If the generated voltage on the LS pin exceeds 7 V, add a Zener diode between the LS and COM2 pins.

High Voltage 3-Phase Motor Drivers

SX6800xMH ELECTRICAL CHARACTERISTICS Valid $T_A = 25$ °C; unless otherwise noted

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Logic Supply Current	I _{CC}	V _{CC} = 15 V, I _{REG} = 0 A	_	4.6	8.5	mA
Bootstrap Supply Current	I _B	VB = 15 V, HIN = 5 V per phase	_	140	400	μΑ
Input Voltage	V _{IH}	V _{CC} = 15 V, Output on	_	2	2.5	V
Input voltage	V _{IL}	V _{CC} = 15 V, Output off	1	1.5	_	V
FO Input Threshold Voltage	V _{FOIH}	V _{CC} = 15 V, Output on	_	2	2.5	V
FO input Threshold voltage	V_{FOIL}	V _{CC} = 15 V, Output off	1	1.5	_	V
Input Current	I _{IH}	V _{CC} = 15 V, V _{IN} = 5 V	_	230	500	μΑ
Input Current	I _{IL}	V _{IN} = 0 V	_	-	2	μΑ
High-Side Undervoltage Lock Out	V _{UVHL}	Patusan VP and LL V as W	9.0	10.0	11.0	V
High-Side Offdervoltage Lock Out	V _{UVHH}	Between VB and U, V, or W	9.5	10.5	11.5	V
Law Cida Hadamalkana Laak Out	V _{UVLL}	Detugen VCC and COM	10.0	11.0	12.0	V
Low-Side Undervoltage Lock Out	V _{UVLH}	Between VCC and COM	10.5	11.5	12.5	V
FO Townsing I Output Voltage	V _{FOL}	V - 45 V V - 5 V D - 40 k0	0	_	0.5	V
FO Terminal Output Voltage	V _{FOH}	V_{CC} = 15 V, V_{FO} = 5 V, R_{FO} = 10 k Ω	4.8	_	_	V
Output limit Output Valtage	V _{OCLL}	V - 45 V	0	_	0.5	V
Overcurrent Limit Output Voltage	V _{OCLH}	V _{CC} = 15 V		_	5.5	V
Current Limit Reference Voltage	V _{LIM}	V _{CC} = 15 V	0.6175	0.65	0.6825	V
Overcurrent Protection Trip Voltage	V _{TRIP}	V _{CC} = 15 V	0.9	1.0	1.1	V
Overcurrent Protection Hold Time	t _P	V _{CC} = 15 V	20	25	_	μs
Overcurrent Protection Blanking Time	t _{bk(ocp)}	V _{CC} = 15 V	_	2	_	μs
Overcurrent Limit Blanking Time	t _{bk(ocl)}	V _{CC} = 15 V	_	2	_	μs
SD Terminal Blanking Time	t _{bk(SD)}	V _{CC} = 15 V	_	3.3	_	μs
Overtemperature Protection Activating	T _{DH}	V = 45 V no hootsink and L = 0 no 0	135	150	165	°C
and Releasing Temperature	T _{DL}	V_{CC} = 15 V, no heatsink and I_{REG} = 0 mA	105	120	135	°C
Output Voltage for Regulator	V _{REG}	I _{REG} = 35 mA	6.75	7.5	8.25	V
		SX68001MH V _R = 250 V	_	_	10	μΑ
Bootstrap Diode Leakage Current	I _{LBD}	SX68002MH V _R = 500 V	_	_	10	μΑ
		SX68003MH V _R = 500 V	_	_	10	μΑ
Bootstrap Diode Forward Voltage	V _{FBD}	I _F = 0.15 A	_	1.0	1.3	V
Bootstrap Diode Series Resistor	R _{BD}		48	60	72	Ω
		SX68001MH V _{DS} = 250 V	_	_	100	μA
MOSFET Leakage Current	I _{DSS}	SX68002MH V _{DS} = 500 V	_	_	100	μA
		SX68003MH V _{DS} = 500 V	_	_	100	μA
		SX68001MH V _{CC} = 15 V, I _D = 1 A, V _{IN} = 5 V	_	1.25	1.5	Ω
MOSFET On State Resistance	R _{DS(on)}	SX68002MH V _{CC} = 15 V, I _D = 0.75 A, V _{IN} = 5 V	_	3.2	4.0	Ω
	35(5)	SX68003MH V _{CC} = 15 V, I _D = 1.25 A, V _{IN} = 5 V	_	2.0	2.4	Ω
		SX68001MH V _{CC} = 15 V, I _{SD} = 1 A, V _{IN} = 0 V	_	1.1	1.5	V
Diode Forward Voltage (MOSFET)	V _{SD}	SX68002MH V _{CC} = 15 V, I _{SD} = 0.75 A, V _{IN} = 0 V	_	1.0	1.5	V
		SX68003MH V _{CC} = 15 V, I _{SD} = 1.25 A, V _{IN} = 0 V	_	1.0	1.5	V

High Voltage 3-Phase Motor Drivers

SX68001MH SWITCHING CHARACTERISTICS Valid T_A = 25°C; unless otherwise noted

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
High-Side Switching Time	t _{dH(on)}		ı	800	_	ns
	t _{rH}	V _{BB} = 150 V, V _{CC} = 15 V, I _D = 1 A, 0 V < V _{IN} < 5 V, see	_	45	_	ns
	t _{rrH}	Switching Time Definition diagram	-	75	-	ns
	t _{dH(off)}		_	720	-	ns
	t _{fH}		_	40	_	ns
	t _{dL(on)}	V_{BB} = 150 V, V_{CC} = 15 V, I_{D} = 1 A, 0 V < V_{IN} < 5 V, see Switching Time Definition diagram	_	750	_	ns
	t _{rL}		_	50	-	ns
Low-Side Switching Time	t _{rrL}		-	70	-	ns
	t _{dL(off)}		-	660	-	ns
	t _{fL}		-	20	-	ns

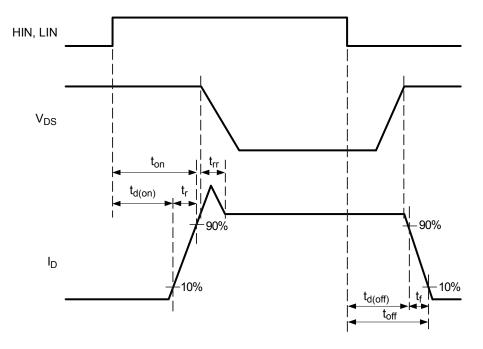
SX68002MH SWITCHING CHARACTERISTICS Valid $T_A = 25$ °C; unless otherwise noted

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
High-Side Switching Time	t _{dH(on)}	V _{BB} = 300 V, V _{CC} = 15 V, I _D = 0.75 A, 0 V < V _{IN} < 5 V,	ı	810	_	ns
	t_{rH}		-	60	_	ns
	t _{rrH}	see Switching Time Definition diagram	ı	120	_	ns
	t _{dH(off)}		ı	815	_	ns
	t _{fH}		-	40	-	ns
	t _{dL(on)}	V_{BB} = 300 V, V_{CC} = 15 V, I_{D} = 0.75 A, 0 V < V_{IN} < 5 V, see Switching Time Definition diagram	-	760	-	ns
	t_{rL}		_	60	_	ns
Low-Side Switching Time	t _{rrL}		_	110	_	ns
	t _{dL(off)}		_	750	_	ns
	t _{fL}		_	30	_	ns

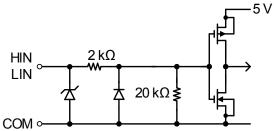
SX68003MH SWITCHING CHARACTERISTICS Valid T_A = 25°C; unless otherwise noted

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
	t _{dH(on)}	V _{BB} = 300 V, V _{CC} = 15 V, I _D = 1.25 A, 0 V < V _{IN} < 5 V,	-	940	_	ns
High-Side Switching Time	t _{rH}		ı	100	_	ns
	t _{rrH}	see Switching Time Definition diagram	_	135	_	ns
	t _{dH(off)}		ı	975	_	ns
	t _{fH}		_	45	-	ns
	t _{dL(on)}	V_{BB} = 300 V, V_{CC} = 15 V, I_{D} = 1.25 A, 0 V < V_{IN} < 5 V, see Switching Time Definition diagram	ı	900	_	ns
	t _{rL}		-	105	_	ns
Low-Side Switching Time	t _{rrL}		-	135	_	ns
	t _{dL(off)}		-	905	_	ns
	t _{fL}		_	35	-	ns

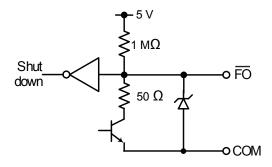
Switching Time Definition



HIN, LIN Internal Equivalent Circuit

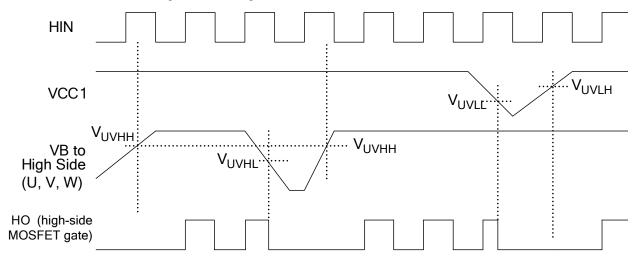


FO Internal Equivalent Circuit

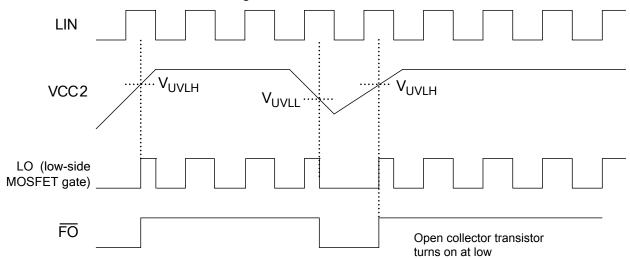


Protection Circuit Timing

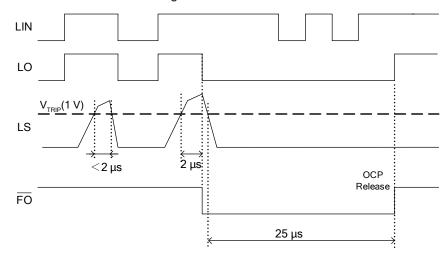
UVLO Protection Circuit - High Side Timing



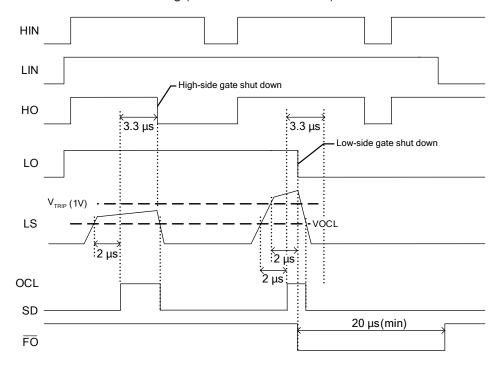




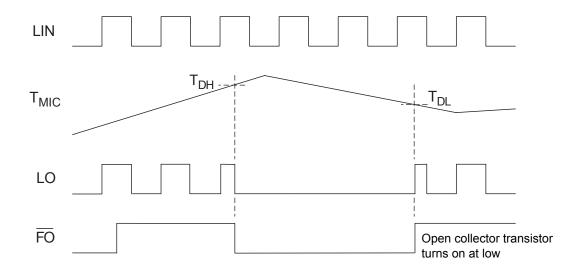
OCP Protection CircuitTiming



OCL Protection CircuitTiming (OCL and SD connected)

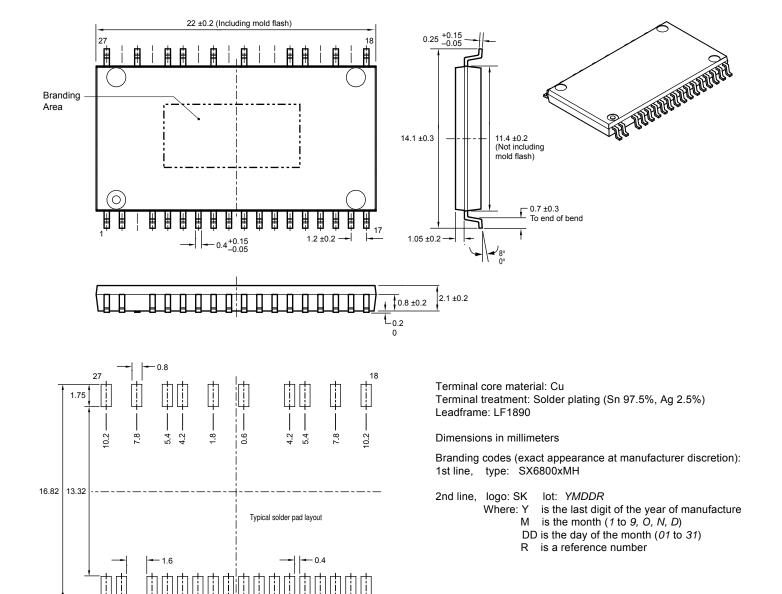


TSD Protection CircuitTiming



High Voltage 3-Phase Motor Drivers

Package Outline Drawing, SOP-27



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High Voltage 3-Phase Motor Drivers

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40% to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of the products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between the product pins, and wrong connections. Ensure all test parameters are within the ratings specified by Sanken for the products.

Soldering

• When soldering the products, please be sure to minimize the working time, within the following limits:

260°±5°C 10 s 380°±5°C 5 s, using soldering iron

Electrostatic Discharge

- When handling the products, the operator must be grounded. Grounded wrist straps worn should have at least 1 M Ω of resistance from the operator to ground to prevent shock hazard, and it should be placed near the operator.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons
 or the solder bath must be grounded in order to prevent
 leak voltages generated by them from being applied to the
 products.
- The products should always be stored and transported in Sanken shipping containers or conductive containers, or be wrapped in aluminum foil.

High Voltage 3-Phase Motor Drivers

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